NSN 5961-00-868-4260

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Inclosure Material:

Metal

Overall Length:

0.300 inches

Overall Diameter:

0.830 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 collector to base voltage, dc and 400.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc

Current Rating Per Characteristic:

2.00 amperes source cutoff current

Power Rating Per Characteristic:

125.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

2 pin and 1 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0